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Customer Number

Patent
Case No.: 59001US002**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**First Named Inventor: **WOLK, MARTIN B.**Application No.: **10/731199** Group Art Unit: **1752**Filed: **December 9, 2003** Examiner: **Richard L. Schilling**Title: **THERMAL TRANSFER OF LIGHT-EMITTING DENDRIMERS****AFFIDAVIT UNDER 37 C.F.R. 1.131**

STATE OF MINNESOTA)

)

COUNTY OF RAMSEY)

)

I, Martin B. Wolk, being duly sworn, does hereby depose and say as follows:

1. I am the Applicant of the above-identified patent application and the sole inventor of the subject matter described and claimed therein.

2. Prior to February 27, 2003, I completed the invention as described and claimed in the above-identified application in this country, the United States of America, as evidenced by the following:

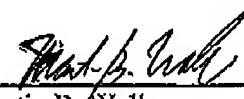
a. Prior to February 27, 2003, I made, or at my direction had made, a device as described in Claim 1 of U.S. Patent Application Attorney Docket No. 59001US007 (Serial No. 11/074268, filed March 7, 2005) by following the steps of the method described in Claim 1 of U.S. Patent Application Attorney Docket No. 59001US002 (Serial No. 10/731199, filed December 9, 2003). Evidence of the device and method used to make the device can be found in pages 58-62 of my Lab Notebook No. 129169, a copy of which is attached as Exhibit A.

b. From pages 58-62 of my Lab Notebook No. 129169, it can be seen that several devices were made by using a laser induced thermal imaging (LITI) processes to transfer, from donors to receptors, portions of various formulations of transfer layers including dendrimers.

3. Each of the dates deleted from Exhibit A is prior to February 27, 2003.

4. I acknowledge that willful false statements and the like are punishable by fine or imprisonment, or both, (18 U.S.C. § 1001) and may jeopardize the validity of the application or any patent issuing thereon. All statements made in this Affidavit of my own knowledge are true and all statements made on information and belief are believed to be true.

FURTHER AFFIANT SAYETH NOT.



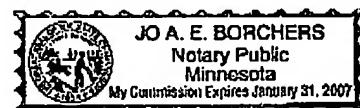
Martin B. Wolk

Sworn to and subscribed before me by the above-named Applicant,
this 9th day of February, 2006.



Notary Public

seal



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NOTEBOOK NO.PAGE
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1 PROJECT NO.

SUBJECT:

DATE:

Objective:

PROJECT NO. 0022998005
NOTEBOOK NO. 129169

LITI OLED

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5 Reference:

Dendrimers versus "Soluble Triplet Emitters"

Purpose: This experiment involved reproducing the high efficiency devices that were prepared during the Opsys visit of In addition, we compared our current best molecular film formulation with the formulation used in September.

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Description: The experiment compared the performance of conventional and LITI devices using Covion Ir(ppy)₃-SC4 (Covion ID# IDB 3009) and Opsys Ir(ppy)₃-D (Opsys ID# HSA 35) at equimolar concentrations. The molecular weight of the Covion material is 967.3 g/mol and the molecular weight of the dendrimer (from published Opsys data) is 2108.9 g/mol.

All solution preparation and coating will be done in the glovebox. Imaging will be done by briefly removing the substrates from the box and returning them to the box until cathode deposition is scheduled.

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The experiment parameters are as follows:

Emitter Type 1: Covion Ir(ppy)₃-SC4 (Covion ID# IDB 3009)
Emitter Type 2: Opsys Ir(ppy)₃-D (Opsys ID# HSA 35)

Formulation Type 1: spiro-CBP-S1:emitter 80:20 (w/w, dendrimer), 90:8:9.2 (w/w, Covion)
Formulation Type 2: EL028T/spiro-CF₃PBD/EM 45:45:10 (w/w/w, Covion), 39.1:39.1:21.8 (w/w/w, dendrimer)

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ITO Coating Type 1: SiO₂
ITO Coating Type 2: EL111T (160 nm)

Device Type 1: spin coated conventional (SiO₂ buffer only)
Device Type 2: LITI device

Cathode: TPBi/LiF/AI/Ag (500/10/40/4000 Å)

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Experiment Samples:

Tables 1 and 2 indicate the device types generated in this experiment. In addition, a series of dosing experiments were carried out in order to prepare the LITI devices. Dosing slides were prepared for each device type in Table 2.

Table 1: Spin Coated Device Types (in triplicate)

Emitter	Formulation	ITO Coating
1 (Covion)	1	SiO ₂
2 (Opsys)	1	SiO ₂
1 (Covion)	2	SiO ₂
2 (Opsys)	2	SiO ₂

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AUTHOR'S INITIALS	MJW	DATE
WITNESS'S INITIALS	JFB	DATE 3/5/03

AUTHOR'S FULL NAME or INITIALS MJW DATE: _____

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Table 2: LITI Device Types (in triplicate)

Emitter formulation	ITO coating
1 (Covion)	1 SiO ₂
1 (Covion)	1 EL111T
2 (Opsys)	1 SiO ₂
2 (Opsys)	1 EL111T
1 (Covion)	2 SiO ₂
1 (Covion)	2 EL111T
2 (Opsys)	2 SiO ₂
2 (Opsys)	2 EL111T

Summary of 021203 Averaged Coupon Data
(@ 400 Cd/m²)

DATE	CONSTRUCTION	TYPE	VOLTAGE	CURRENT (mA)	LUMINANCE (Cd/m ²)	GOODS (%)	DEFECTS (%)	REMARKS
021203-01	MF/Covion	Conv	5.13	1.68	24.0	1		
021203-02	MF/Covion	"	6.26	2.48	16.2	3		
021203-04	MF/Opsys	"	4.81	1.36	29.3	2		
021203-05	MF/Opsys	"	5.20	1.68	24.0	3		
021203-07	sCBP/Covion	"	6.89	2.32	17.3	3		
021203-08	sCBP/Covion	"	6.73	2.16	18.5	3		
021203-09	sCBP/Covion	"	7.12	2.58	15.5	3		
021203-10	sCBP/Opsys	"	6.70	1.71	23.9	2		
021203-11	sCBP/Opsys	"	6.46	1.28	32.5	3		
021203-12	sCBP/Opsys	"	5.97	1.20	34.2	3		
021203-32	MF/Covion	LITI	4.95	1.06	37.7	3	44	
021203-33	MF/Covion	"	4.91	1.05	38.1	1		
021203-34	MF/Covion	"	5.26	1.11	36.1	2		
021203-38	MF/Opsys	"	5.18	1.17	34.3	3	26	
021203-39	MF/Opsys	"	5.31	1.16	34.7	3	36	
021203-40	MF/Opsys	"	5.53	1.18	33.9	1		
021203-41	MF/Opsys	"	5.26	1.16	34.6	3	31	
021203-44	sCBP/Covion	"	5.40	1.01	39.9	4	12	
021203-45	sCBP/Covion	"	6.56	1.48	27.2	2		
021203-46	sCBP/Covion	"	5.75	1.20	33.8	3		
021203-50	sCBP/Opsys	"	10.54	1.42	28.2	1		
021203-51	sCBP/Opsys	"	5.62	1.37	29.3	2		
021203-52	sCBP/Opsys	"	5.79	1.27	31.5	3		
021203-63	MF/Covion	"	5.99	1.56	25.6	2		
021203-66	sCBP/Opsys	"	7.45	1.51	26.5	3	5	
021203-68	sCBP/Covion	"	6.78	1.76	22.7	1		
021203-69	sCBP/Covion	"	7.87	1.85	24.3	2		
021203-70	sCBP/Opsys	"	7.33	1.43	28.0	2		

AUTHOR'S INITIALS *MPL* DATEWITNESS'S INITIALS *JRC* DATE 8/5/03AUTHOR'S FULL NAME or INITIALS *MPL* DATEWITNESS'S FULL NAME or INITIALS *JRC* DATE 8/5/03

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1 PROJECT NO.

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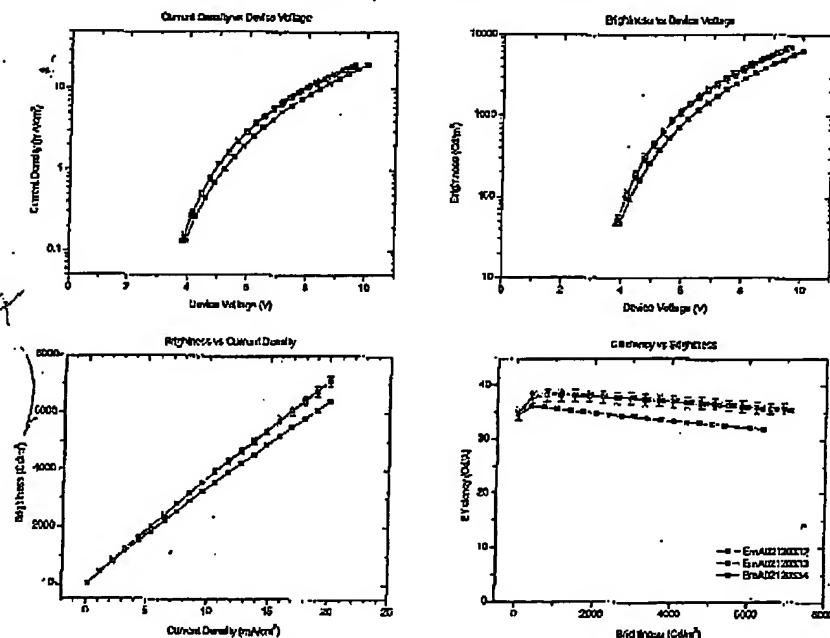
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Summary of 021203 Averaged Data by Device Type
(@ 400 Cd/m²)

Device Type	Sample	Current Density (mA/cm ²)	Brightness (Cd/m ²)	Efficiency (%)	Power (mW)
MF/Covion	conv	5.70	2.08	20.14	4.00
MF/Covion	LITI	5.28	1.19	34.38	8.00
MF/Opsys	conv	5.00	1.52	26.67	5.00
MF/Opsys	LITI	5.32	1.17	34.33	10.00
sCBP/Covion	conv	6.91	2.36	17.12	9.00
sCBP/Covion	LITI	6.47	1.42	29.55	12.00
sCBP/Opsys	conv	6.38	1.40	30.18	8.00
sCBP/Opsys	LITI	7.34	1.40	28.70	11.00

LIV Data Plots for Three Samples

Averaged Data (MDF/Covion/TPBI)



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mgw

DATE

WITNESS'S INITIALS

Jmw

DATE 3/5/03

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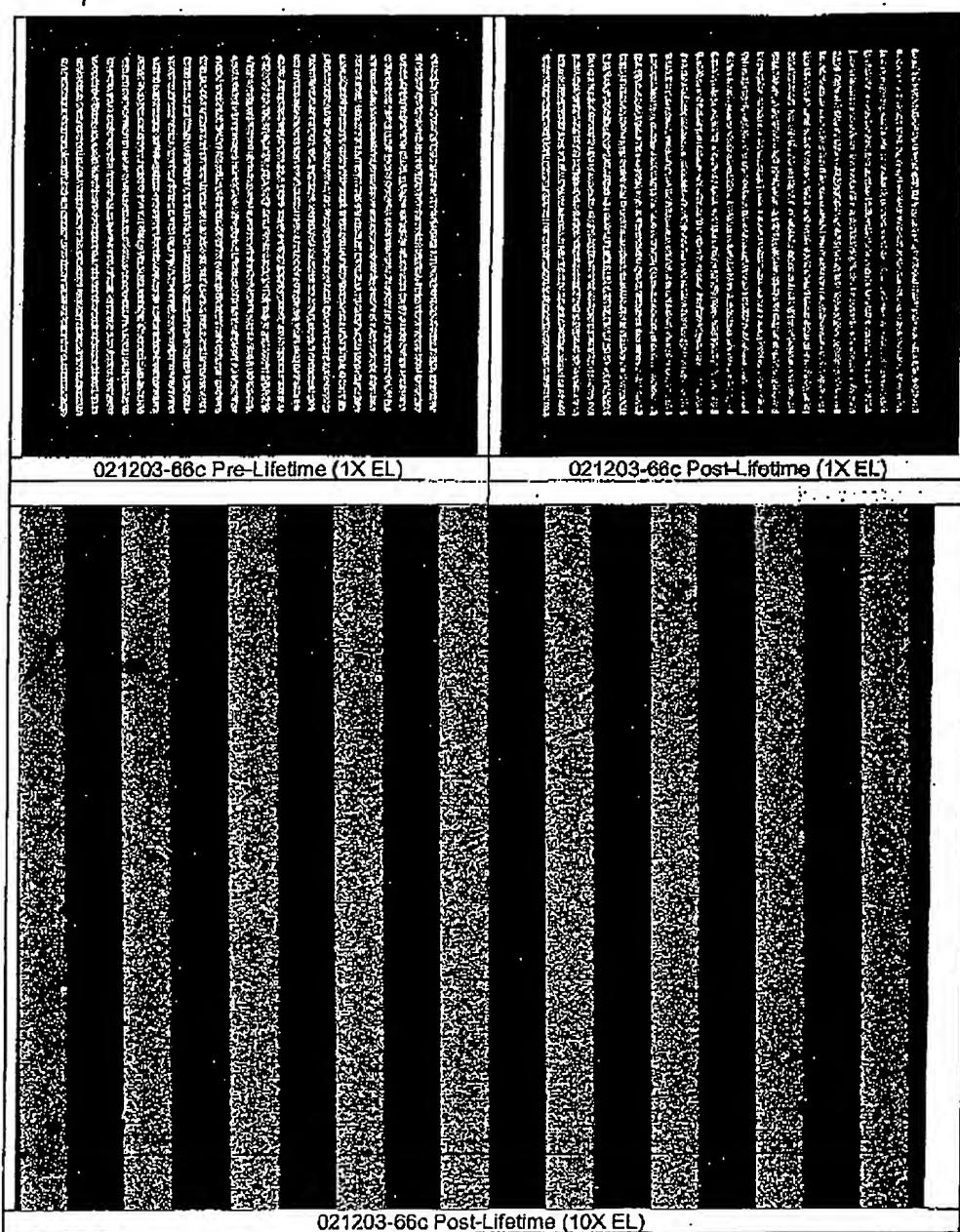
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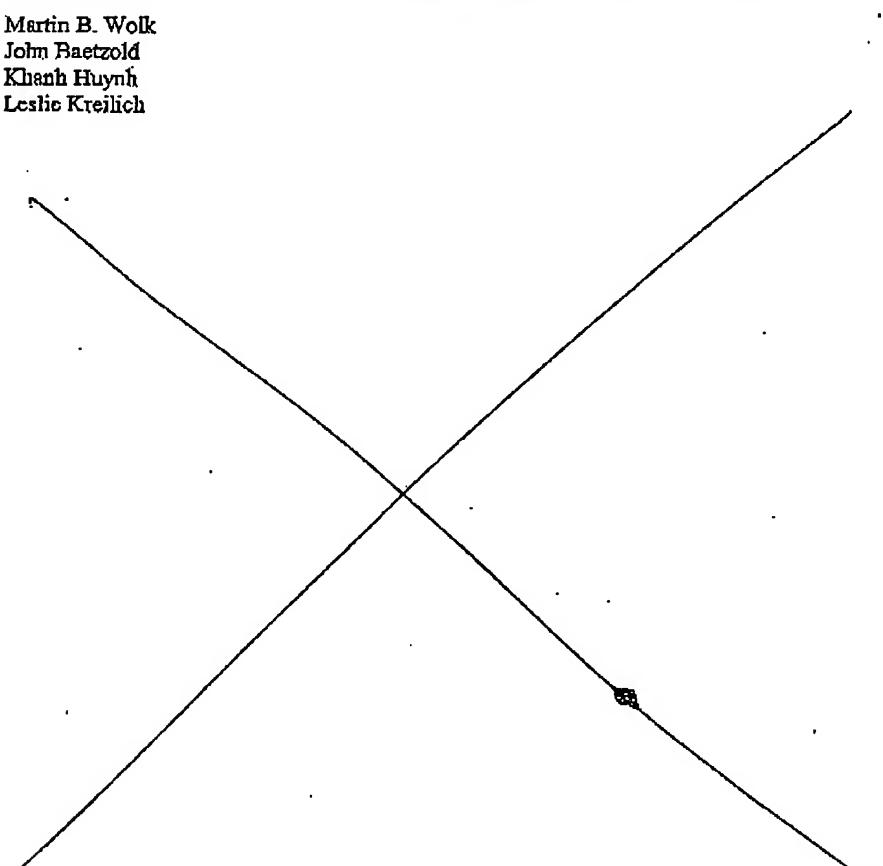
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10	Objective:	PROJECT NO. 0022998005 NOTEBOOK NO. 129169
15	5 Reference:	Comments and Conclusions: We successfully reproduced the results of September by preparing high efficiency devices based on the Opsys dendrimer. We also prepared LITI devices of equal quality. Furthermore, we demonstrated that devices with similar, if not identical, performance could be prepared with the Covion soluble emitter. The lifetime results were poor. All devices failed within 70 hours at 400 cd/m ² . EL micrographs were examined before and after the lifetime experiment. No gross defects were found – just an overall dimming and a very slight mottling. The portion of the experiment dealing with the HB layer (TPBI versus BAQ) was omitted due to problems during the BAQ cathode runs. The effect of TPBI on lifetime is unknown at this point. Future experiments will concentrate on improving lifetime of these high efficiency devices.
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